NSN 5961-01-023-9950

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Inclosure Material:

Metal

Overall Length:

0.188 inches

Terminal Length:

0.500 inches

Overall Diameter:

0.219 inches

Internal Configuration:

Junction contact

Mounting Method:

Terminal

Terminal Circle Diameter:

0.100 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

40.0 breakdown voltage, collector-to-base, emitter open and 40.0 breakdown voltage, collector-to-emitter, base open and 4.0 breakdown voltage, emitter-to-base, collector open

Power Rating Per Characteristic:

300.0 milliwatts small-signal input power, common-collector

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Junction pattern arrangement: npn

Terminal Type And Quantity:

4 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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